## SIEMENS

## IRED in TO-Package

- InGaAsP/InP - IRED
- Designed for application in fiber-optic
- Datacom systems
- Transmitter for the $2^{\text {nd }}$ optical window ( 1300 nm )
- Suitable for bit rates up to $50 \mathrm{Mbit} / \mathrm{s}$
- $200 \mathrm{Mbit} / \mathrm{s}$ with appropriate pulse shaping of the modulation current
- High output power with double heterostructure
- High coupling efficiency into multimode fibers
- No z-adjustment necessary (optimum coupling on cap surface)
- Hermetically sealed 3-pin metal case


| Type | Ordering Code | Connector/Flange |
| :--- | :--- | :--- |
| STL 39002Z | Q62702-P3009 | TO, with optics |

## Maximum Ratings

| Parameter | Symbol | Values | Unit |
| :--- | :--- | :---: | :--- |
| Forward current (DC) | $I_{\mathrm{F}}$ | 60 | mA |
| Forward current $(\tau \leq 10 \mu \mathrm{~s}, \mathrm{D} \leq 1)$ | $I_{\mathrm{FSM}}$ | 100 | mA |
| Reverse voltage | $V_{\mathrm{R}}$ | 0.5 | V |
| Operating and storage temperature | $T_{\mathrm{A}}, T_{\mathrm{stg}}$ | $-40 \ldots+85$ | ${ }^{\circ} \mathrm{C}$ |
| Junction temperature | $T_{\mathrm{j}}$ | 125 | ${ }^{\circ} \mathrm{C}$ |
| Soldering time (wave / dip soldering), <br> distance between solder point and base plate <br> $\geq 2 \mathrm{~mm}, 260^{\circ} \mathrm{C}$ | $t_{\mathrm{S}}$ | 10 | s |

## Characteristics

All optical data refer to an ambient temperature of $25^{\circ} \mathrm{C}$.

| Parameter | Symbol | Values | Unit | Notes |
| :---: | :---: | :---: | :---: | :---: |
| Emission wavelength | $\lambda c$ | $1310 \pm 30$ | nm | 1 |
| Spectral bandwidth at $50 \%$ of $\Phi_{\text {max }}$ | $\Delta \lambda$ | $130 \pm 30$ | nm | 1 |
| Opt. power coupled into $62.5 \mu \mathrm{~m}$ multimode fiber, $N A=0.27$ | $\Phi_{\mathrm{e}}$ | - 17.5 ... - 13.5 | dBm | 1.2 |
| Opt. power coupled into $50 \mu \mathrm{~m}$ multimode fiber, NA $=0.2$ | $\Phi_{\mathrm{e}}$ | - 20.5 ... - 16.5 | dBm | 1.2 |
| Forward voltage, $I_{F}=50 \mathrm{~mA} \mathrm{DC}$ | $V_{F}$ | $1.2(\leq 1.5)$ | V |  |
| Rise and fall time ( $10 \%-90 \%$ ) $R_{\mathrm{L}}=50 \Omega, I_{\mathrm{F}}=50 \mathrm{~mA}$ | $t_{r} ; t_{\text {f }}$ | 3; 4 | ns |  |
| Capacitance $V_{\mathrm{R}}=0, f=1 \mathrm{MHz}$ | $C_{0}$ | 100 | pF |  |
| Temp. coefficient of forward voltage, $I_{\mathrm{F}}=50 \mathrm{~mA}$ | $T C_{V F}$ | -1.3 | mV/K |  |
| Temp. coefficient of wavelength, $I_{\mathrm{F}}=50 \mathrm{~mA}$ | $T C_{\lambda}$ | 0.5 | nm/K |  |
| Temp. coefficient of opt. power, $I_{\mathrm{F}}=50 \mathrm{~mA}$ | $T C_{\Phi}$ | -0.7 | \%/K |  |

## Operating Instructions

In order to achieve an operating lifetime $>10^{5} \mathrm{~h}$, which is required for Telcom applications, a forward current of $I_{F}=50 \mathrm{mADC}$ is recommended.
Notes: 1) Driving current is a square wave, $50 \%$ duty cycle, $60 \mathrm{~mA}_{\mathrm{pk}}$ current at 1 MHz . $\Phi_{\mathrm{e}}$ is the average optical power coupled into the specified fiber.
2) Optimum coupling on cap surface, no adjustment in z-axis necessary.

Rel. Spectral Emission
$\Phi_{\mathrm{e}}=\Phi_{\mathrm{e}}(\lambda)$


## Forward Current $\mathbf{C W}$

$I_{F}=I_{F}\left(T_{A}\right)$


Package Outlines (Dimensions in mm)



## STL 39002Z

